

ULTRA-FAST GLASS PASSIVATED RECTIFIER VOLTAGE RANGE 50 TO 1000 Volts Current 1 Ampere

FEATURES

- * Ultra-fast recovery time for high efficiency
- * Glass Passivated Chip junction
- * Excellent high temperature switching
- * Low leakage
- * High temperature soldering guaranteed 260 /10 seconds, 0.375"(9.5 mm) lead length at 5 lbs(2.3kg) tension

MECHANICAL DATA

* Case: Transfer Molded Plastic

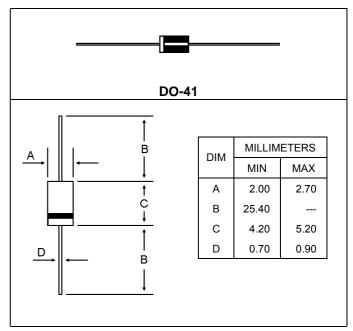
* Epoxy: UL94V-O rate flame retardant

*Terminals: Solderable Per MIL-STD-202 Method 208

* Polarity: Color band denotes cathode end

* Mounting position: Any

* Weight: 0.012 ounce. 0.33 gram (approx)



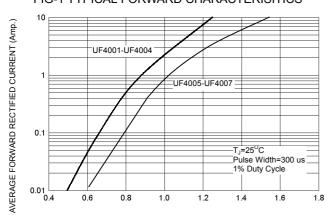
MAXIMUM RATINGS AND ELECTRICAL CHARATERISTICS

- * Rating at 25 ambient temperature unless otherwise specified
- * Single phase, half wave. 60Hz, resistive or inductive load.
- * For capacitive load derate current bh 20 %

Characteristic	Symbol	UF4001	UF4002	UF4003	UF4004	UF4005	UF4006	UF4007	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Average Rectifier Forward Current Per Leg T _C =125	I _{F(AV)}	1.0							Α
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I _{FSM}	30							А
Maximum Instantaneous Forward Voltage ($I_F = 1.0 \text{ Amp } T_C = 25$)	V _F	1.3							V
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25$) (Rated DC Voltage, $T_C = 125$)	I _R	5.0 200							uA
Reverse Recovery Time (I _F = 0.5 A, I _R =1.0 , I _{rr} =0.25 A)	T _{rr}	50 75						ns	
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	C _j	18							pF
Typical Thermal Resistance	R_{\thetajA}	60							/W
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +175							

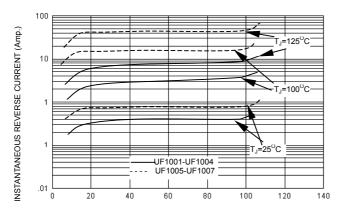
UF4001 Thru UF4007

FIG-1 TYPICAL FORWARD CHARACTERISITICS

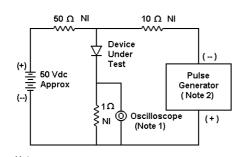


FORWARD VOLTAGE (Volts)

FIG-2 TYPICAL REVERSE CHARACTERISTICS



PERCENT OF PEAK REVERSE VOLTAGE (%)



1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50 Ω

FIG-3 FORWARD CURRENT DERATING CURVE

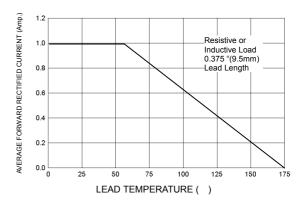


FIG-4TYPICAL JUNCTION CAPACITANCE

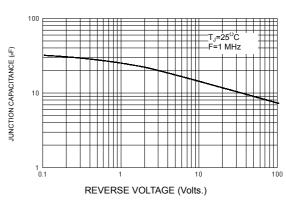
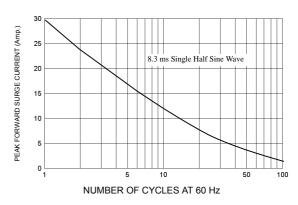


FIG-5PEAK FORWARD SURGE CURRENT



+0.5A 0 -0.25A

Set time base for 20/50 ns/cm

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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